

## Read / Write Base Station IC

### Description

The U2270B is an IC for IDIC<sup>®\*</sup> read/write base stations in contactless identification and immobilizer systems.

The IC incorporates the energy-transfer circuit to supply the transponder. It consists of an on-chip power supply, an

oscillator and a coil driver optimized for automotive-specific distances. It also includes all signal-processing circuits which are necessary to form the small input signal into a microcontroller-compatible signal.

### Features

- Carrier frequency  $f_{osc}$  100 kHz – 150 kHz
- Typical data rate up to 5 kbaud at 125 kHz
- Suitable for Manchester and Bi-phase modulation
- Power supply from the car battery or from 5-V regulated voltage
- Optimized for car immobilizer applications
- Tuning capability
- Microcontroller-compatible interface
- Low power consumption in standby mode
- Power-supply output for microcontroller

### Applications

- Car immobilizers
- Animal identification
- Access control
- Process control
- Further industrial applications

### Ordering Information

Extended Type Number	Package	Remarks
U2270B-FP	SO16	

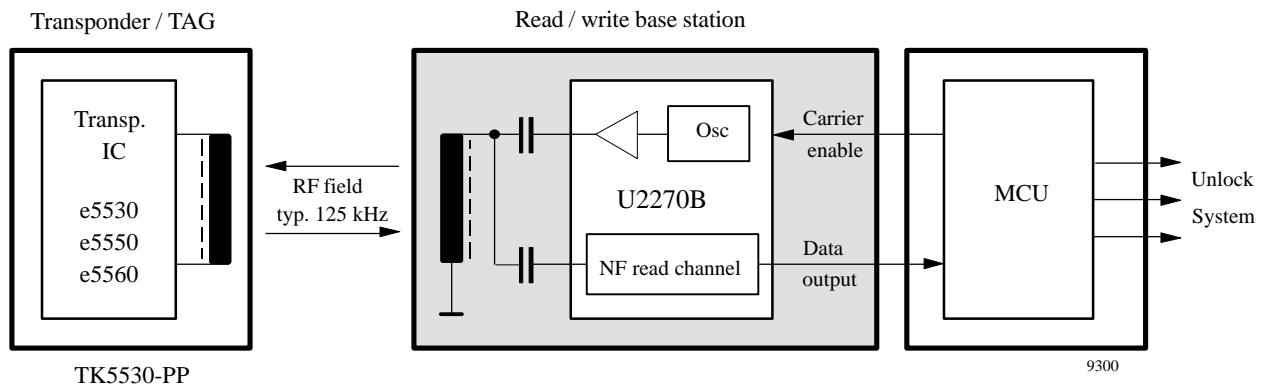
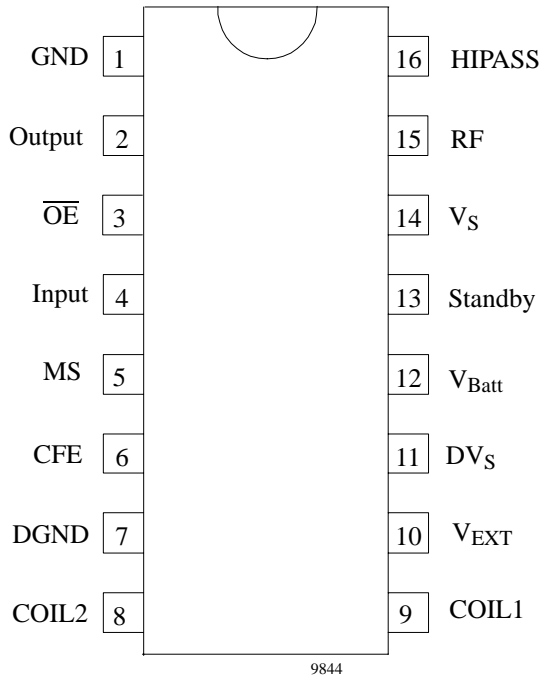


Figure 1.

\*) IDIC<sup>®</sup> stands for **ID**entification **I**ntegrated **C**ircuit and is a trademark of TEMIC Semiconductors.

## Pin Description



Pin	Symbol	Function
1	GND	Ground
2	Output	Data output
3	$\overline{\text{OE}}$	Data output enable
4	Input	Data input
5	MS	Mode select coil 1: Common mode / Differential mode
6	CFE	Carrier frequency enable
7	DGND	Driver ground
8	COIL 2	Coil driver 2
9	COIL 1	Coil driver 1
10	$V_{\text{EXT}}$	External power supply
11	$DV_S$	Driver supply voltage
12	$V_{\text{Batt}}$	Battery voltage
13	Standby	Standby input
14	$V_S$	Internal power supply (5 V)
15	RF	Frequency adjustment
16	HIPASS	DC decoupling

Figure 2. Pinning

## Block Diagram

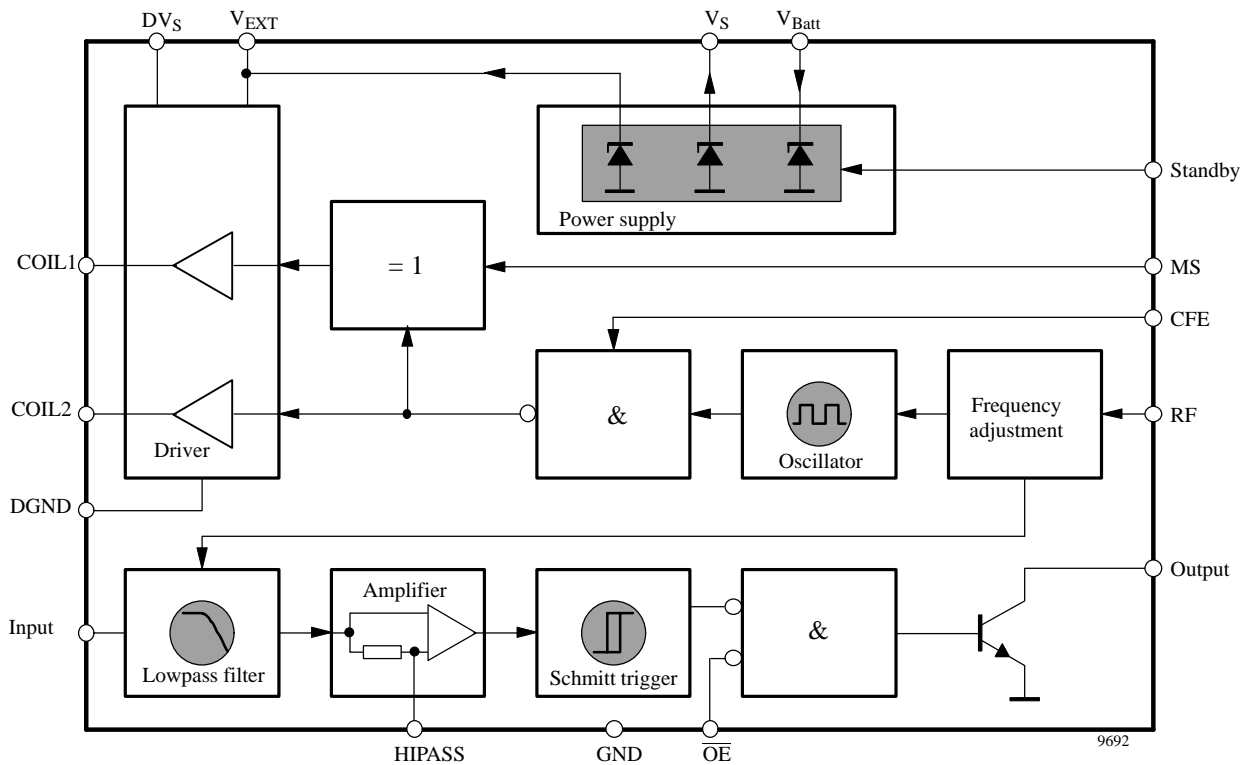


Figure 3.

**Functional Description**

**Power Supply (PS)**

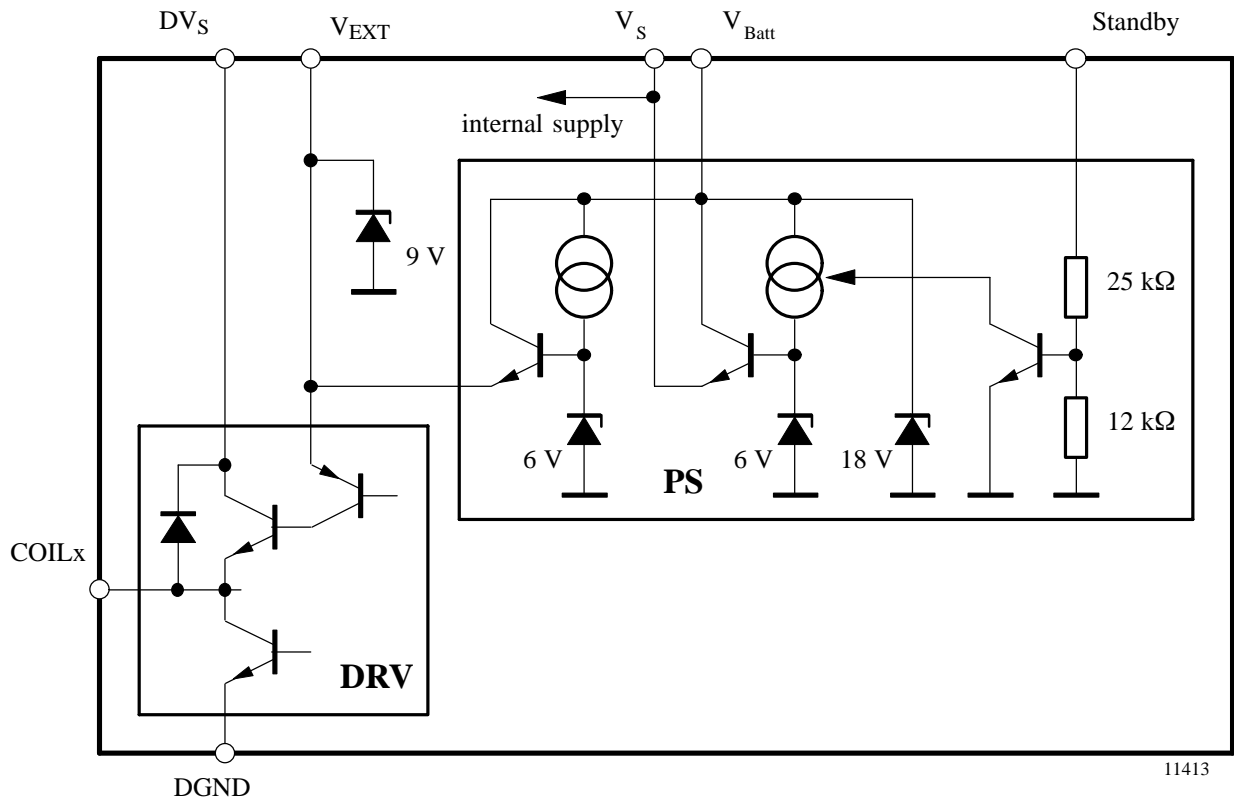


Figure 4. Equivalent circuit of power supply and antenna driver

The U2270B can be operated with one external supply voltage or with two externally-stabilized supply voltages for an extended driver output voltage or from the 12-V battery voltage of a vehicle. The 12-V supply capability is achieved via the on-chip power supply (see figure 4). The power supply provides two different output voltages,  $V_S$  and  $V_{EXT}$ .

$V_S$  is the internal power supply voltage except for the driver circuit. Pin  $V_S$  is used to connect a block capacitor.  $V_S$  can be switched off by the Pin Standby. In standby mode, the chip's power consumption is very low.  $V_{EXT}$  is the supply voltage of the antenna's pre-driver. This voltage can also be used to operate external circuits, i.e., a microcontroller. In conjunction with an external NPN transistor it also establishes the supply voltage of the antenna coil driver,  $DVS$ .

The following section explains the 3 different operation modes to power the U2270B.

### 1. One-rail operation

All internal circuits are operated from one 5-V power rail. (see figure 5). In this case,  $V_S$ ,  $V_{EXT}$  and  $DV_S$  serve as inputs.  $V_{Batt}$  is not used but should also be connected to that supply rail.

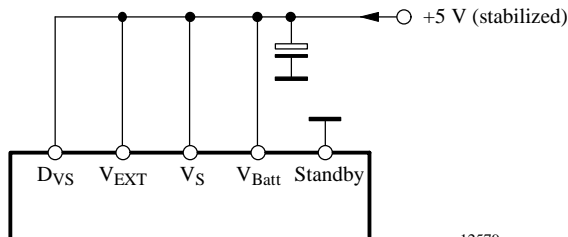


Figure 5.

### 2. Two-rail operation

In this application, the driver voltage,  $DV_S$ , and the pre-driver supply,  $V_{EXT}$ , are operated at a higher voltage than the rest of the circuitry to obtain a higher driver-output swing and thus a higher magnetic field, (see figure 6).  $V_S$  is connected to a 5-V supply, whereas the driver voltages can be as high as 8 V. This operation mode is intended to be used in situations where an extended communication distance is required.

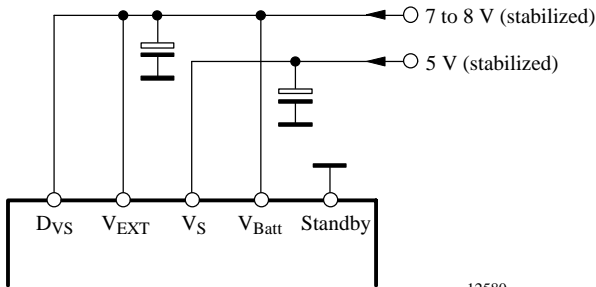


Figure 6.

### 3. Battery-voltage operation

Using this operation mode,  $V_S$  and  $V_{EXT}$  are generated by the internal power supply (see figure 7). For this mode, an external voltage regulator is not needed. The IC can be switched off via the pin Standby.  $V_{EXT}$  supplies the base of an external NPN transistor and external circuits, i.e., a microcontroller (even in Standby mode).

Pin  $V_{EXT}$  and  $V_{Batt}$  are overvoltage protected via internal Zener diodes (see figure 4). The maximum current into the pins is determined by the maximum power dissipation and the maximum junction temperature of the IC.

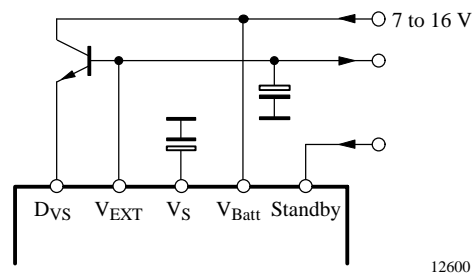


Figure 7.

Table 1. Characteristics of the various operation modes.

Operation Mode	External Components Required	Supply-Voltage Range	Driver Output Voltage Swing	Standby Mode Available
1. One-rail operation	1 Voltage regulator 1 Capacitor	5 V $\pm$ 10%	$\approx$ 4 V	No
2. Two-rail operation	2 Voltage regulators 2 Capacitors	5 V $\pm$ 10% 7 V to 8 V	6 V to 7 V	No
3. Battery-voltage operation	1 Transistor 2 Capacitors Optional for load-dump protection: 1 Resistor 1 Capacitor	6 V to 16 V	$\approx$ 4 V	Yes

### Oscillator (Osc)

The frequency of the on-chip oscillator is controlled by a current fed into the  $R_F$  input. An integrated compensation circuit ensures a wide temperature and supply-voltage-independent frequency which is selected by a fixed resistor between  $R_F$  (Pin 15) and  $V_S$  (Pin 14). For 125 kHz, a resistor value of 110 k $\Omega$  is defined. For other frequencies, use the following formula:

$$R_f/k\Omega = \frac{14375}{f_0/kHz} - 5$$

This input can be used to adjust the frequency close to the resonance of the antenna. For more details refer to the applications and the application note ANT019.

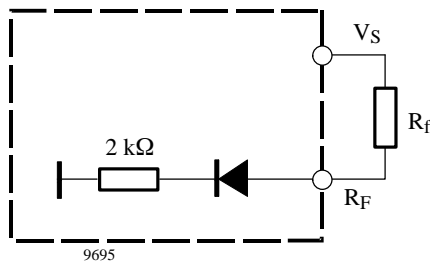


Figure 8. Equivalent circuit of Pin  $R_F$

### Filter (LPF)

The fully-integrated lowpass filter (4th-order butterworth) removes the remaining carrier signal and high-frequency disturbances after demodulation. The upper cut-off frequency of the LPF depends on the selected oscillator frequency. The typical value is  $f_{Osc}/18$ . That means that data rates up to  $f_{Osc}/25$  are possible if Bi-phase or Manchester encoding is used.

A highpass characteristic results from the capacitive coupling at the input Pin 4 as shown in figure 9. The input voltage swing is limited to  $2 V_{pp}$ . For frequency response calculation, the impedances of the signal source and LPF input (typical 220 k $\Omega$ ) have to be considered. The recommended values of the input capacitor for selected data rates are given in the chapter “Applications”.

Note: After switching on the carrier, the DC voltage of the coupling capacitor changes rapidly. When the antenna voltage is stable, the LPF needs approximately 2 ms to recover full sensitivity.

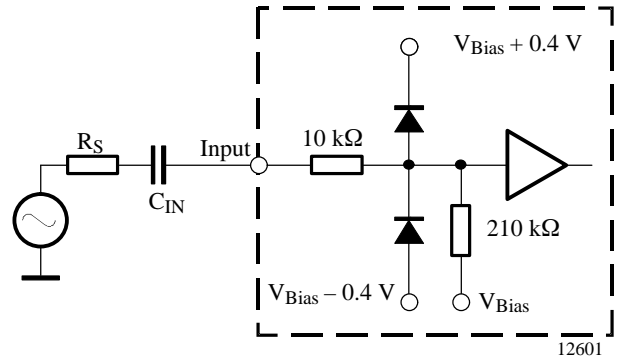


Figure 9. Equivalent circuit of Pin Input

### Amplifier (AMP)

The differential amplifier has a fixed gain, typically 30. The HIPASS pin is used for dc decoupling. The lower cut-off frequency of the decoupling circuit can be calculated as follows:

$$f_{cut} = \frac{1}{2 \times \pi \times C_{HP} \times R_i}$$

The value of the internal resistor  $R_i$  can be assumed to be 2.5 k $\Omega$ .

Recommended values of  $C_{HP}$  for selected data rates can be found in the chapter “Applications”.

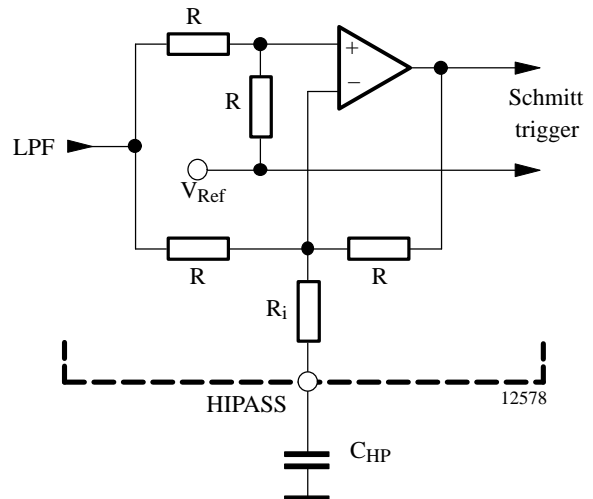


Figure 10. Equivalent circuit of Pin HIPASS

## Schmitt Trigger

The signal is processed by a Schmitt trigger to suppress possible noise and to make the signal  $\mu\text{C}$  compatible. The hysteresis level is 100 mV symmetrically to the DC operation point. The open-collector output is enabled by a low level at  $\overline{\text{OE}}$  (Pin 3).

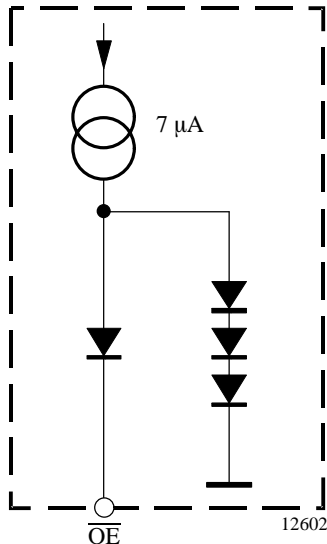


Figure 11. Equivalent circuit of Pin  $\overline{\text{OE}}$

## Driver (DRV)

The driver supplies the antenna coil with the appropriate energy. The circuit consists of two independent output stages. These output stages can be operated in two different modes. In common mode, the outputs of the stages are in phase. In this mode, the outputs can be interconnected to achieve a high-current output capability. Using the differential mode, the output voltages are in anti-phase. Thus, the antenna coil is driven with a higher voltage. For a specific magnetic field, the antenna coil impedance is higher for the differential mode. As a higher coil impedance results in a better system sensitivity, the differential mode should be preferred.

The CFE input is intended to be used for writing data into a read/write or a crypto transponder. This is achieved by interrupting the RF field with short gaps. The various functions are controlled by the inputs MS and CFE (refer to the function table). The equivalent circuit of the driver is shown in figure 4.

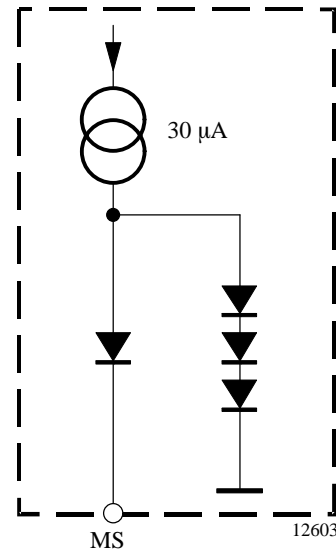


Figure 12. Equivalent circuit of Pin MS

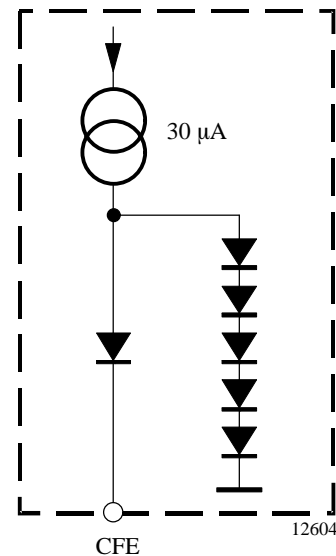

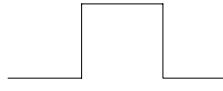
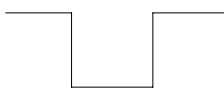
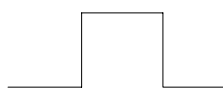


Figure 13. Equivalent circuit of Pin CFE

**Function Table**

CFE	MS	COIL1	COIL2
Low	Low	High	High
Low	High	Low	High
High	Low		
High	High		

OE	Output
Low	Enabled
High	Disabled

Standby	U2270B
Low	Standby mode
High	Active

**Applications**

To achieve the suitable application, consider the power-supply environment and the magnetic-coupling situation.

The selection of the appropriate power-supply operation mode depends on the supply environment. If an unregulated supply voltage in the range of  $V = 7\text{ V}$  to  $16\text{ V}$  is available, the internal power supply of the U2270B can be used. In this case, standby mode can be used and an external low-current  $\mu\text{C}$  can be supplied.

If a 5-V supply rail is available, it can be used to power the U2270B. In this case, please check that the voltage is noise-free. An external power transistor is not necessary.

The application depends also on the magnetic-coupling situation. The coupling factor mainly depends on the transmission distance and the antenna coils. The following table lists the appropriate application for a given coupling factor. The magnetic coupling factor can be determined using TEMIC Semiconductors' test transponder coil.

Magnetic Coupling Factor	Appropriate Application
$k > 3\%$	Free-running oscillator
$k > 1\%$	Diode feedback
$k > 0.5\%$	Diode feedback plus frequency altering
$k > 0.3\%$	Diode feedback plus fine frequency tuning

The maximum transmission distance is also influenced by the accuracy of the antenna's resonance. Therefore, the recommendations given above are proposals only. A good compromise for the resonance accuracy of the antenna is a value in the range of  $f_{\text{res}} = 125\text{ kHz} \pm 3\%$ . Further details concerning the adequate application and the antenna design is provided in chapter "Antenna Design Hints".

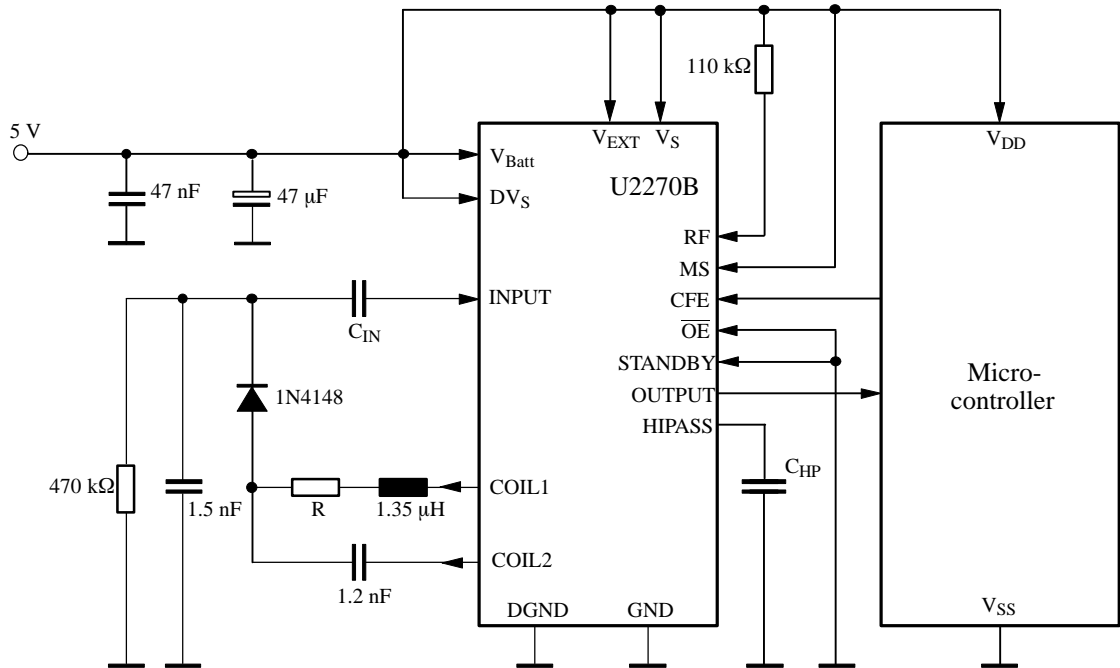
The application of the U2270B includes the two capacitors  $C_{\text{IN}}$  and  $C_{\text{HP}}$  whose values are linearly dependent on the transponder's data rate. The following table gives the appropriate values for the most common data rates. The values are valid for Manchester and Bi-phase code.

Data Rate $f = 125\text{ kHz}$	Input Capacitor ( $C_{\text{IN}}$ )	Decoupling Capacitor ( $C_{\text{HP}}$ )
$f/32 = 3.9\text{ kbit/s}$	680 pF	100 nF
$f/64 = 1.95\text{ kbit/s}$	1.2 nF	220 nF

The following applications are typical examples. The values of  $C_{\text{IN}}$  and  $C_{\text{HP}}$  correspond to the transponder's data rate only. The arrangement to fit the magnetic-coupling situation is also independent from other design issues except for one constellation. This constellation, consisting of diode feedback plus fine frequency tuning together with the two-rail power supply, should be used if the transmission distance of  $d \approx 10\text{ cm}$ .

## Application 1

Application using few external components. This application is for intense magnetic coupling only.

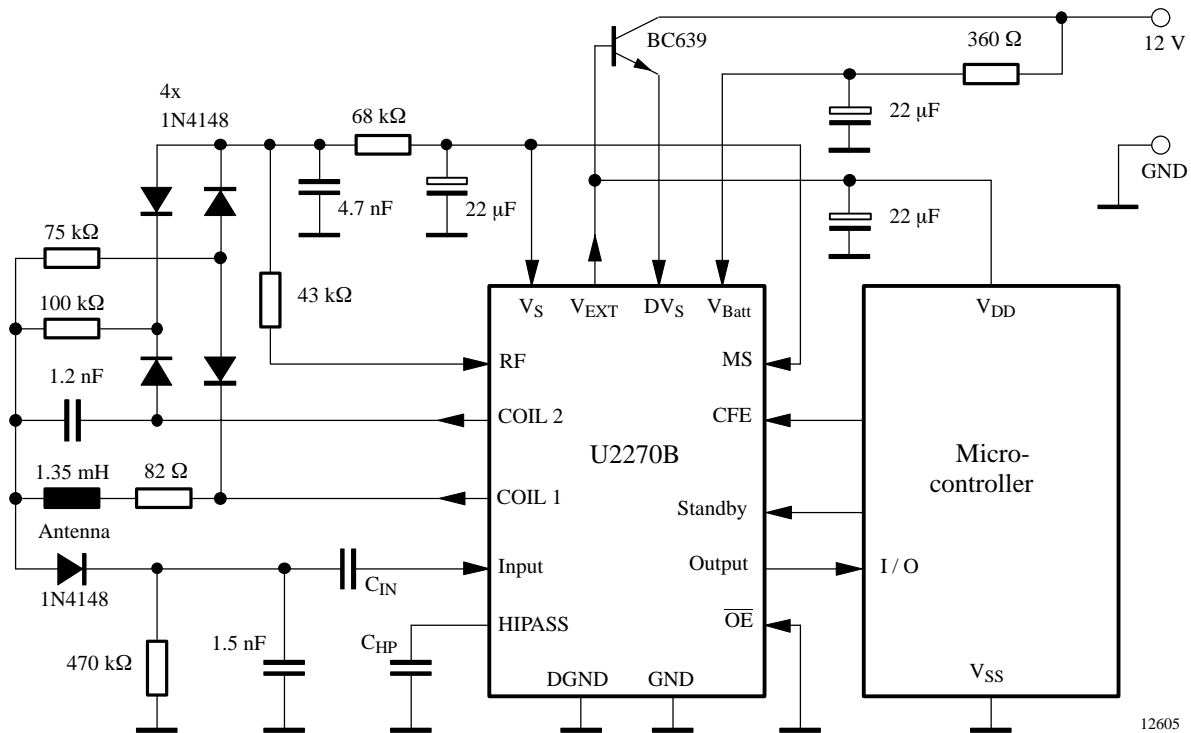


9693

Figure 14. Application circuit

## Application 2

Basic application using diode feedback. This application permits higher communication distances than application 1.



12605

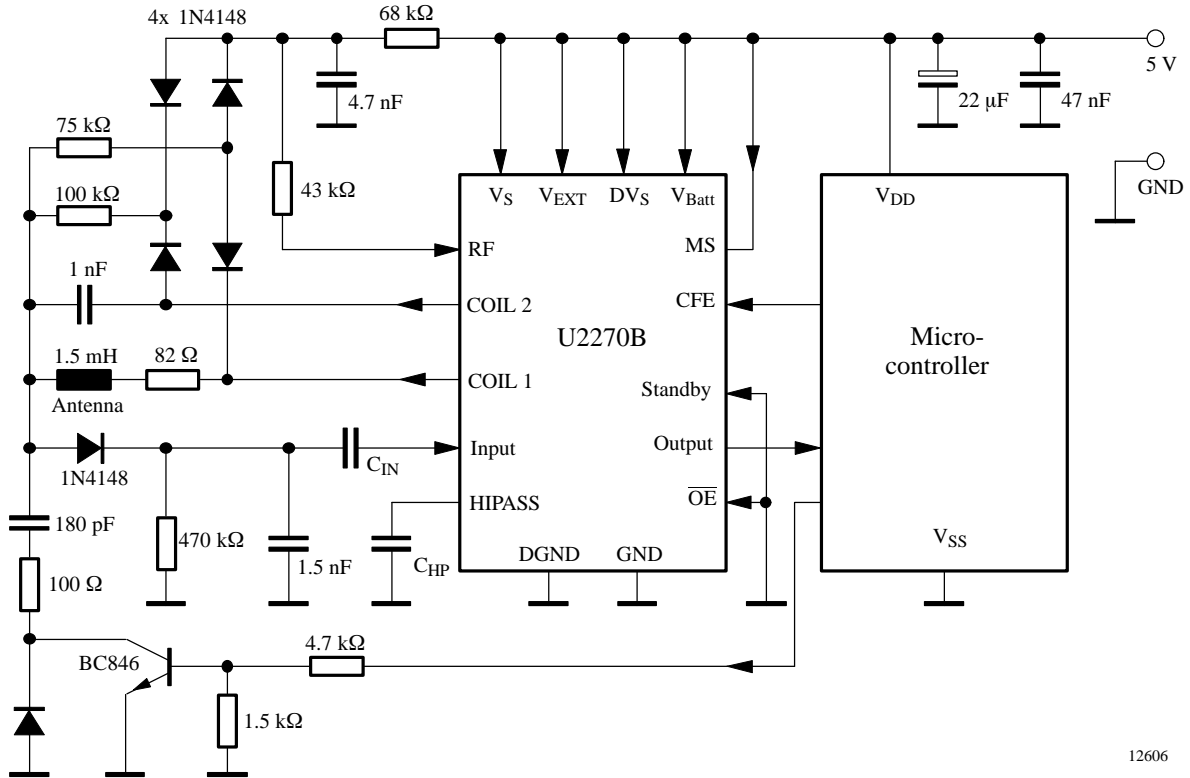
Figure 15. Application circuit



**Application 3**

This application is comparable to application 2 but alters the operating frequency. This permits higher antenna resonance tolerances and/or higher communication

distances. This application is preferred if the detecting  $\mu\text{C}$  is close to the U2270B as an additional  $\mu\text{C}$  signal controls the adequate operating frequency.



12606

Figure 16. Application circuit

**Important note:**

Application examples have not been examined for series use or reliability, and no worst case scenarios have been developed. Customers who adapt any of these proposals must carry out their own testing and be convinced that no negative consequences arise from the proposals.

## Absolute Maximum Ratings

All voltages are referred to GND (Pins 1 and 7).

Parameters/Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit
Operating voltage	Pin 12	$V_{Batt}$	$V_S$		16	V
Operating voltage	Pins 8, 9, 10, 11 and 14	$V_S, V_{EXT}, DV_S, \text{Coil 1, Coil 2}$	-0.3		8	V
Range of input and output voltages	Pins 3, 4, 5, 6, 15 and 16 Pins 2 and 13		-0.3 -0.3		$V_S+0.3$ $V_{Batt}$	V
Output current	Pin 10	$I_{EXT}$			10	mA
Output current	Pin 2	$I_{OUT}$			10	mA
Driver output current	Pins 8 and 9	$I_{Coil}$			200	mA
Power dissipation	SO16	$P_{tot}$			380	mW
Junction temperature		$T_j$			150	°C
Storage temperature		$T_{stg}$	-55		125	°C
Ambient temperature		$T_{amb}$	-40		105	°C

## Thermal Resistance

Parameters/Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit
Thermal resistance	SO16	$R_{thJA}$			120	K/W

## Operating Range

All voltages are referred to GND (Pins 1 and 7)

Parameters/Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit
Operating voltage	Pin 12	$V_{Batt}$	7	12	16	V
Operating voltage	Pin 14	$V_S$	4.5	5.4	6.3	V
Operating voltage	Pin 10 Pin 11	$V_{EXT}$ $DV_S$	4.5		8	
Carrier frequency		$f_{osc}$	100	125	150	kHz

## Electrical Characteristics

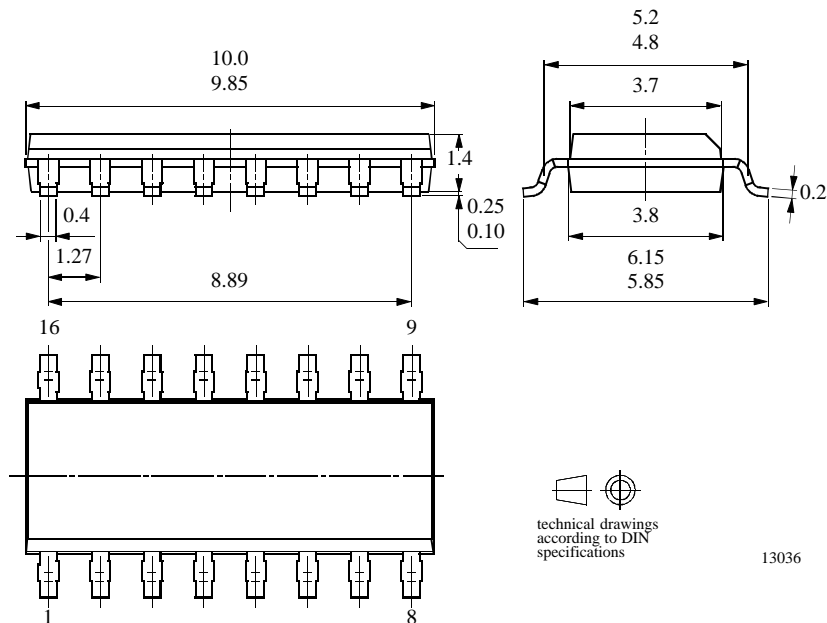
Test conditions (unless otherwise specified):  $V_{Batt} = 12\text{ V}$ ,  $T_{amb} = -40\text{ to }105\text{ }^{\circ}\text{C}$

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Data output – collector emitter saturation voltage	Pin 2 $I_{out} = 5\text{ mA}$	$V_{CEsat}$			400	mV
Data output enable – low-level input voltage – high-level input voltage	Pin 3	$V_{il}$ $V_{ih}$	2.4		0.5	V V
Data input – clamping level low – clamping level high – input resistance – input sensitivity	Pin 4 $f = 3\text{ kHz}$ (squarewave) gain capacitor = 100 nF	$V_{il}$ $V_{ih}$ $R_{in}$ $S_{IN}$	10	2 3.8 220		V V k $\Omega$ mV <sub>pp</sub>
Driver polarity mode – low-level input voltage – high-level input voltage	Pin 5	$V_{il}$ $V_{ih}$	2.4		0.2	V V
Carrier frequency enable – low-level input voltage – high-level input voltage	Pin 6	$V_{il}$ $V_{ih}$	3.0		0.8	V V
Operating current	Pin10, 11, 12 and 14 5-V application without load connected to the coil driver	$I_S$		4.5	9	mA
Standby current	Pin 12 12-V application	$I_{St}$		30	70	$\mu\text{A}$
$V_S$ – Supply voltage – Supply voltage drift – Output current	Pin 14	$V_S$ $dV_S/dT$ $I_S$	4.6 1.8	5.4 4.2 3.5	6.3	V mV/K mA
Driver output voltage – One-rail operation – Battery-voltage operation	$I_L = \pm 100\text{ mA}$ $V_S, V_{EXT}, V_{Batt}, DV_S = 5\text{ V}$ $V_{Batt} = 12\text{ V}$ Pins 8 and 9	$V_{DRV}$ $V_{DRV}$	2.9 3.1	3.6 4.0	4.3 4.7	$V_{pp}$ $V_{pp}$
$V_{ext}$ – Output voltage – Supply voltage drift – Output current – Standby output current	Pin 10 IC active standby mode	$V_{EXT}$ $dV_{EXT}/dT$ $I_{EXT}$ $I_{EXT}$	4.6 3.5 0.4	5.4 4.2	6.3	V mV/K mA mA
Standby input – low-level input voltage – high-level input voltage	Pin 13	$V_{il}$ $V_{ih}$	3.1		0.8	V V
Oscillator – Carrier frequency	RF resistor = 110 k $\Omega$ (application 2), REM 1. *)	$f_0$	121	125	129	kHz
Lowpass filter – Cut-off frequency	Carrier freq. = 125 kHz	$f_{cut}$		7		kHz
Amplifier – Gain	$C_{HP} = 100\text{ nF}$			30		
Schmitt trigger – Hysteresis voltage				100		mV

\*) REM 1.: In application 1. where the oscillator operates in free-running mode, the IC must be soldered free from distortion. Otherwise, the oscillator frequency may be out of bounds.

## Package Information

Package SO16  
Dimensions in mm



---

## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify TEMIC Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

**Data sheets can also be retrieved from the Internet: <http://www.temic-semi.com>**

TEMIC Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany  
Telephone: 49 (0)7131 67 2594, Fax number: 49 (0)7131 67 2423